

N-channel 25 V, 2.09 mΩ, 179 A logic level MOSFET in LFPAK56 using NextPowerS3 Technology 23 April 2021 Product dat

Product data sheet

1. General description

Logic level gate drive N-channel enhancement mode MOSFET in LFPAK56 package. NextPowerS3 portfolio utilising Nexperia's unique "SchottkyPlus" technology delivers high efficiency, low spiking performance usually associated with MOSFETS with an integrated Schottky or Schottky-like diode but without problematic high leakage current. NextPowerS3 is particularly suited to high efficiency applications at high switching frequencies.

2. Features and benefits

- 100% Avalanche tested at $I_{(AS)}$ = 118 A
- Ultra low Q_G, Q_{GD} and Q_{OSS} for high system efficiency, especially at higher switching frequencies
- Superfast switching with soft-recovery
- Low spiking and ringing for low EMI designs
- Unique "SchottkyPlus" technology; Schottky-like performance with < 1 μA leakage at 25 °C
- Optimised for 4.5 V gate drive
- Low parasitic inductance and resistance
- High reliability clip bonded and solder die attach Power SO8 package; no glue, no wire bonds, qualified to 175 °C
- Wave solderable; exposed leads for optimal visual solder inspection

3. Applications

- On-board DC:DC solutions for server and telecommunications
- · Secondary-side synchronous rectification in telecommunication applications
- Voltage regulator modules (VRM)
- Point-of-Load (POL) modules
- Power delivery for V-core, ASIC, DDR, GPU, VGA and system components
- Brushed and brushless motor control

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	-	25	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	-	179	А
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	-	115	W
Tj	junction temperature			-55	-	175	°C
Static chara	acteristics		·	·			
R _{DSon}	drain-source on-state resistance	V _{GS} = 4.5 V; I _D = 25 A; T _j = 25 °C; Fig. 10		-	2.41	2.91	mΩ
		V_{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 10		-	1.82	2.09	mΩ

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Dynamic ch	naracteristics	· · ·	I			
Q _{G(tot)}	total gate charge	I _D = 25 A; V _{DS} = 12 V; V _{GS} = 10 V; Fig. 12; Fig. 13	-	34.1	-	nC
		I _D = 25 A; V _{DS} = 12 V; V _{GS} = 4.5 V; Fig. 12; Fig. 13	-	15.7	-	nC
		I _D = 0 A; V _{DS} = 0 V; V _{GS} = 10 V	-	15.2	-	nC
Q _{GD}	gate-drain charge	I _D = 25 A; V _{DS} = 12 V; V _{GS} = 4.5 V; Fig. 12; Fig. 13	-	3.6	-	nC
Source-drai	in diode	·				
S	softness factor	$I_{S} = 25 \text{ A}; \text{ dI}_{S}/\text{dt} = -100 \text{ A/s}; \text{ V}_{GS} = 0 \text{ V};$ $\text{V}_{DS} = 12 \text{ V}; \frac{\text{Fig. 16}}{100}$	-	1	-	

[1] 179A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	mb	D
2	S	source		
3	S	source	a	G-(FA)
4	G	gate		mbb076 S
mb	D	mounting base; connected to drain	LFPAK56; Power- SO8 (SOT669)	

6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
PSMN2R0-25YLD	LFPAK56; Power-SO8	plastic, single-ended surface-mounted package; 4 terminals	SOT669			

7. Marking

Table 4. Marking codes				
Type number	Marking code			
PSMN2R0-25YLD	2D025L			

8. Limiting values

Table 5. Limiting values

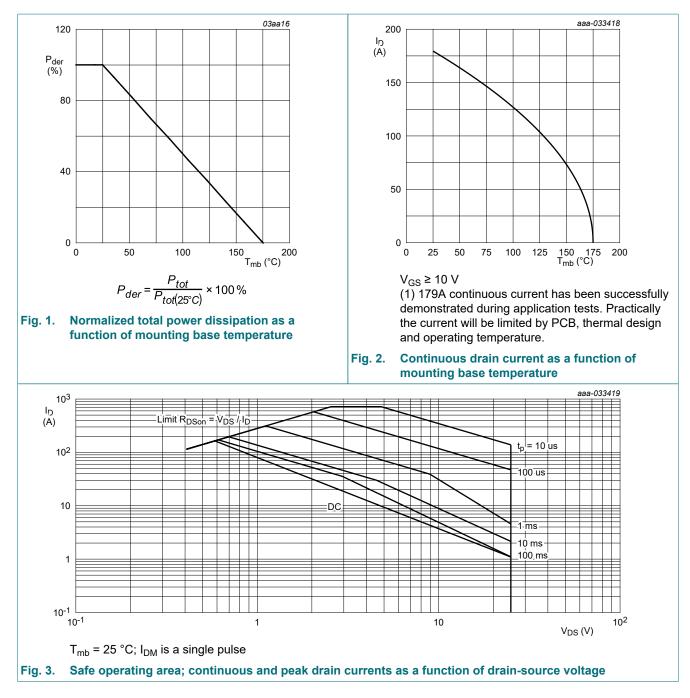
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	25	V
V _{DGR}	drain-gate voltage	25 °C ≤ T_j ≤ 175 °C; R_{GS} = 20 kΩ		-	25	V
V _{GS}	gate-source voltage			-20	20	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	115	W
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	179	А
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 2</u>		-	127	А
I _{DM}	peak drain current	pulsed; t _p ≤ 10 µs; T _{mb} = 25 °C; <u>Fig. 3</u>		-	722	А
T _{stg}	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C
T _{sld(M)}	peak soldering temperature			-	260	°C
V _{ESD}	electrostatic discharge voltage	HBM (JEDEC)		600	-	V
Source-drai	n diode	1		I		
I _S	source current	T _{mb} = 25 °C		-	95	А
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$		-	722	А
Avalanche r	uggedness					
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	$ \begin{array}{l} I_{D} = 25 \; \text{A}; \; V_{sup} \leq \; 25 \; \text{V}; \; \text{R}_{GS} = 50 \; \Omega; \\ V_{GS} = 10 \; \text{V}; \; \text{T}_{j(init)} = 25 \; ^{\circ}\text{C}; \; \text{unclamped}; \\ t_{p} = 1.01 \; \text{ms} \end{array} $		-	410	mJ
I _{AS}	non-repetitive avalanche current		[2]	-	118	A

[1] 179A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

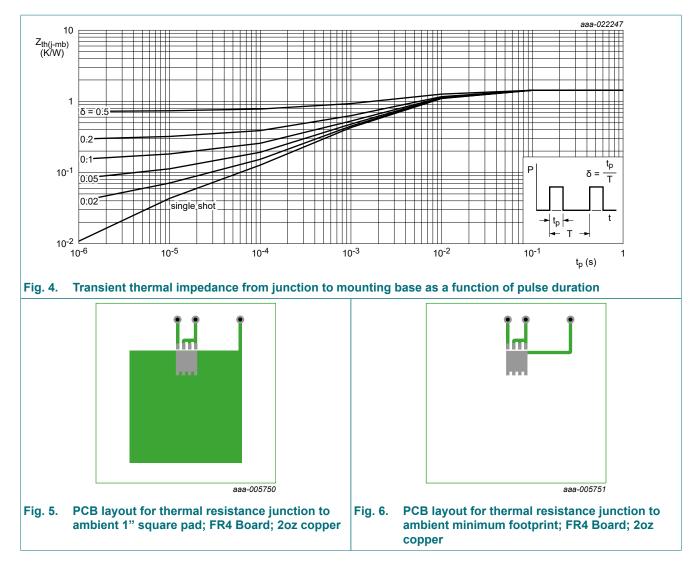
[2] Protected by 100% test

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9. Thermal characteristics

Table 6. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	<u>Fig. 4</u>		-	1.09	1.31	K/W
R _{th(j-a)}	thermal resistance from	<u>Fig. 5</u>		-	50	-	K/W
ju	junction to ambient	<u>Fig. 6</u>		-	125	-	K/W

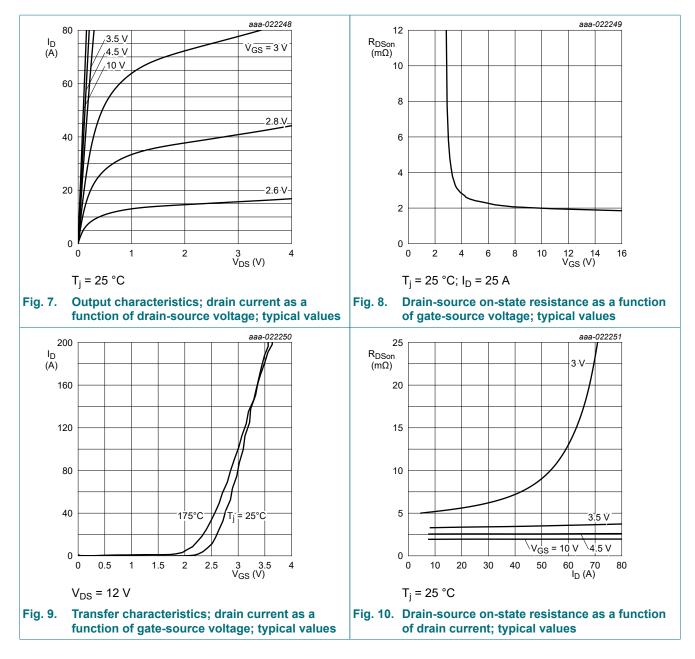


10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static charac	cteristics		I			
breakdow	drain-source	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	25	-	-	V
	breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = -55 °C	22.5	-	-	V
V _{GS(th)}	gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	1.2	1.68	2.2	V
$\Delta V_{GS(th)} / \Delta T$	gate-source threshold voltage variation with temperature	25 °C ≤ T _j ≤ 175 °C	-	-4.5	-	mV/K
I _{DSS}	drain leakage current	V _{DS} = 20 V; V _{GS} = 0 V; T _j = 25 °C	-	-	1	μA
		V _{DS} = 20 V; V _{GS} = 0 V; T _j = 125 °C	-	3.9	-	μA
I _{GSS}	gate leakage current	V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
		V _{GS} = -20 V; V _{DS} = 0 V; T _i = 25 °C	-	-	100	nA

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
R _{DSon}	drain-source on-state resistance	V _{GS} = 4.5 V; I _D = 25 A; T _j = 25 °C; Fig. 10		-	2.41	2.91	mΩ
		V _{GS} = 4.5 V; I _D = 25 A; T _j = 175 °C; Fig. 10; Fig. 11		-	-	4.95	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; <u>Fig. 10</u>		-	1.82	2.09	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 175 °C; Fig. 10; Fig. 11		-	-	3.52	mΩ
R _G	gate resistance	f = 1 MHz		-	0.849	-	Ω
Dynamic ch	naracteristics						
Q _{G(tot)}	total gate charge	I _D = 25 A; V _{DS} = 12 V; V _{GS} = 10 V; Fig. 12; Fig. 13		-	34.1	-	nC
		I _D = 25 A; V _{DS} = 12 V; V _{GS} = 4.5 V; Fig. 12; Fig. 13		-	15.7	-	nC
		I _D = 0 A; V _{DS} = 0 V; V _{GS} = 10 V		-	15.2	-	nC
Q _{GS}	gate-source charge	I _D = 25 A; V _{DS} = 12 V; V _{GS} = 4.5 V;		-	6.4	-	nC
Q _{GS(th)}	pre-threshold gate- source charge	Fig. 12; Fig. 13		-	3.8	-	nC
Q _{GS(th-pl)}	post-threshold gate- source charge			-	2.6	-	nC
Q _{GD}	gate-drain charge			-	3.6	-	nC
V _{GS(pl)}	gate-source plateau voltage	I _D = 25 A; V _{DS} = 12 V; <u>Fig. 12</u> ; <u>Fig. 13</u>		-	2.8	-	V
C _{iss}	input capacitance	V _{DS} = 12 V; V _{GS} = 0 V; f = 1 MHz;		-	2485	-	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 14</u>		-	1142	-	pF
C _{rss}	reverse transfer capacitance	_		-	152	-	pF
t _{d(on)}	turn-on delay time	$V_{DS} = 12 \text{ V}; \text{ R}_{L} = 0.6 \Omega; \text{ V}_{GS} = 4.5 \text{ V};$		-	15.7	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega$		-	18.7	-	ns
t _{d(off)}	turn-off delay time			-	18.7	-	ns
t _f	fall time			-	12.4	-	ns
Q _{oss}	output charge	V _{GS} = 0 V; V _{DS} = 12 V; f = 1 MHz; T _j = 25 °C		-	23	-	nC
Source-drai	in diode						
V _{SD}	source-drain voltage	I_{S} = 20 A; V_{GS} = 0 V; T_{j} = 25 °C; <u>Fig. 15</u>		-	0.8	1.2	V
t _{rr}	reverse recovery time	$I_{S} = 25 \text{ A}; \text{ dI}_{S}/\text{dt} = -100 \text{ A/s}; V_{GS} = 0 \text{ V};$		-	26	-	ns
Q _r	recovered charge	V _{DS} = 12 V; <u>Fig. 16</u>	[1]	-	16.8	-	nC
t _a	reverse recovery rise time			-	13	-	ns
t _b	reverse recovery fall time			-	13	-	ns
S	softness factor			-	1	-	

[1] Includes capacitive recovery

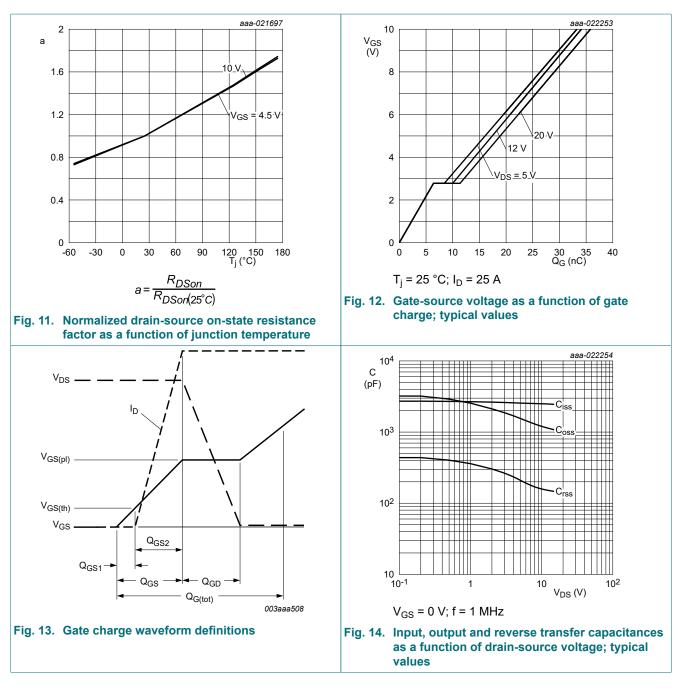


Product data sheet

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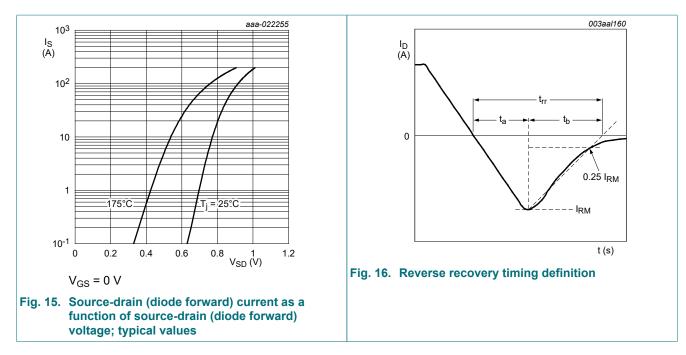
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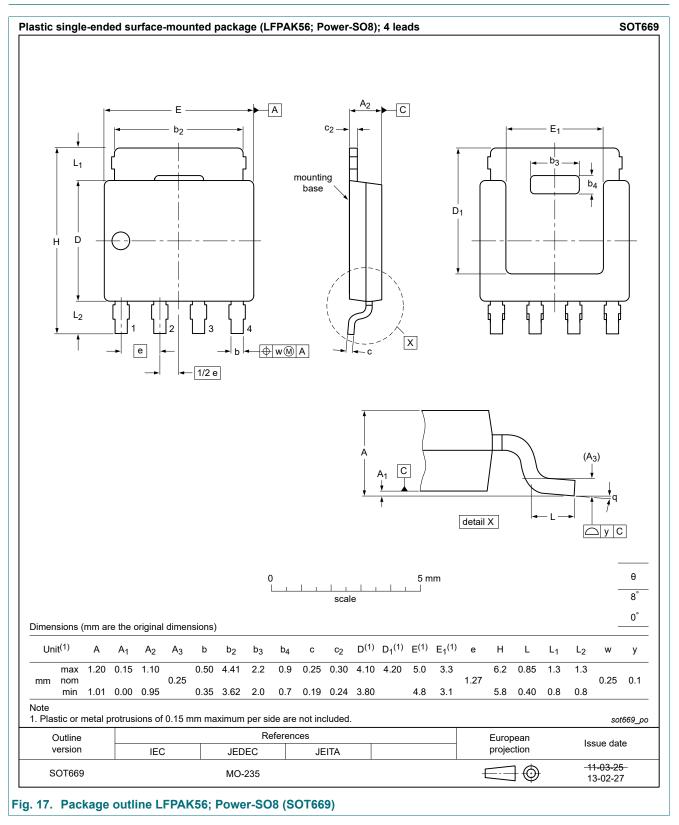


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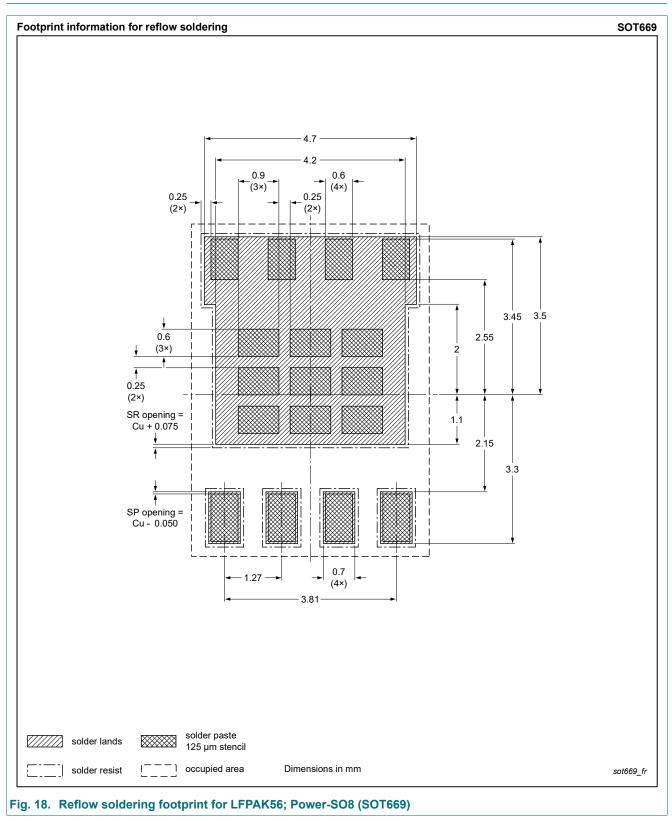
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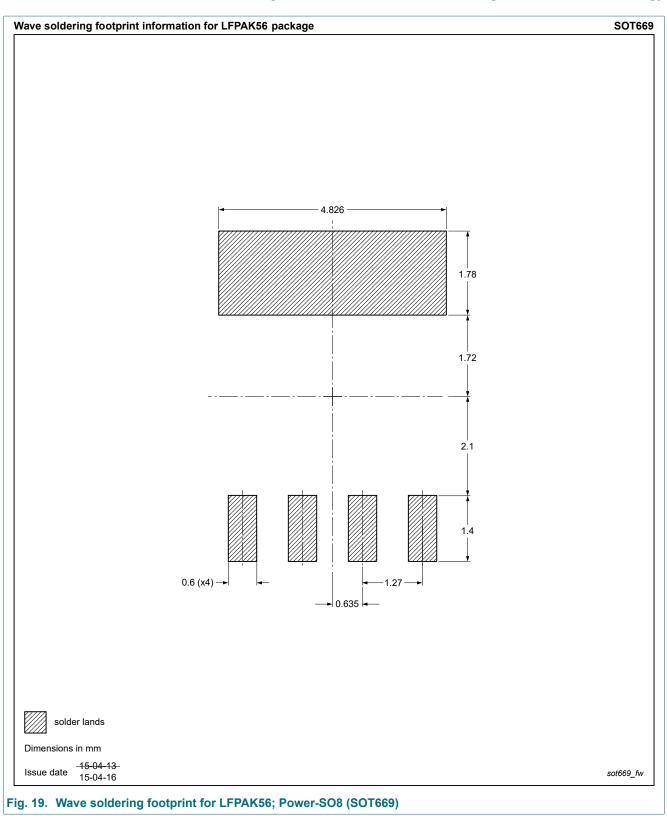
11. Package outline



12. Soldering



N-channel 25 V, 2.09 mΩ, 179 A logic level MOSFET in LFPAK56 using NextPowerS3 Technology



13. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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 Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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